



Slotted Photointerrupters

LTH-301A/LTH-301-05/LTH-301-07/LTH-301-19
 LTH-301-23/LTH-301-32/LTH-306-01/LTH-306-02

Features

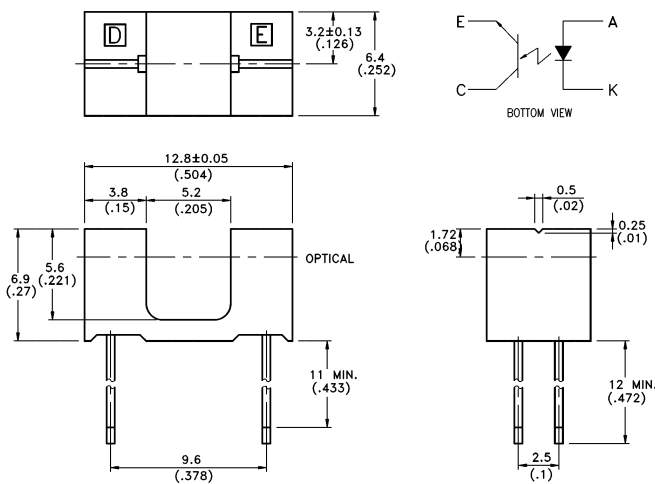
- Non-contact switching.
- For direct PC board or dual-in-line socket mounting.
- Fast switching speed.

Description

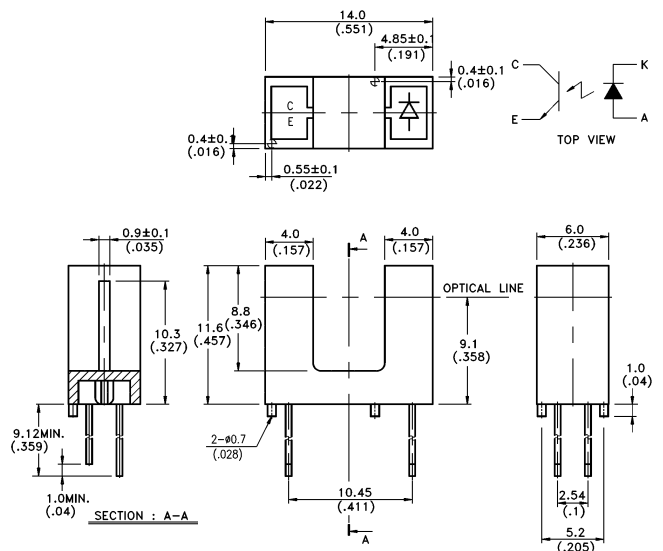
The LTH-301/LTH-306 series consist of Gallium Arsenide infrared emitting diode and a NPN silicon phototransistor mounted in a black plastic housing. Phototransistor switching takes place whenever an opaque object passes through the slot. These series are designed for direct soldering into PC board or mounting in standard dual-in-line socket.

Package Dimensions

LTH-301A



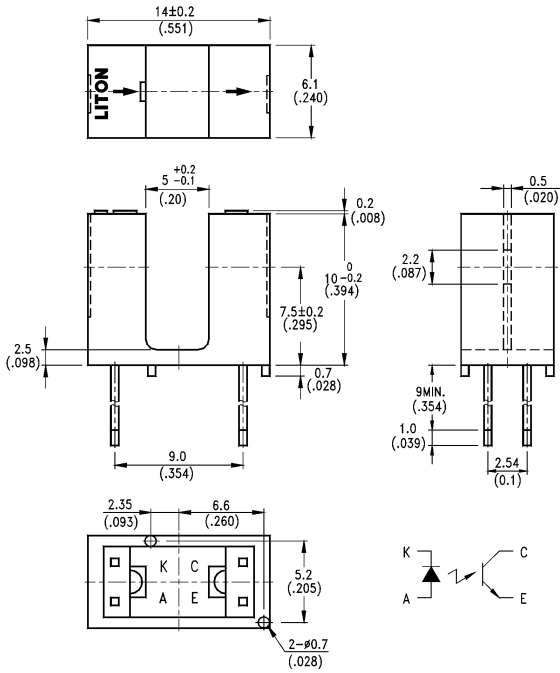
LTH-301-05



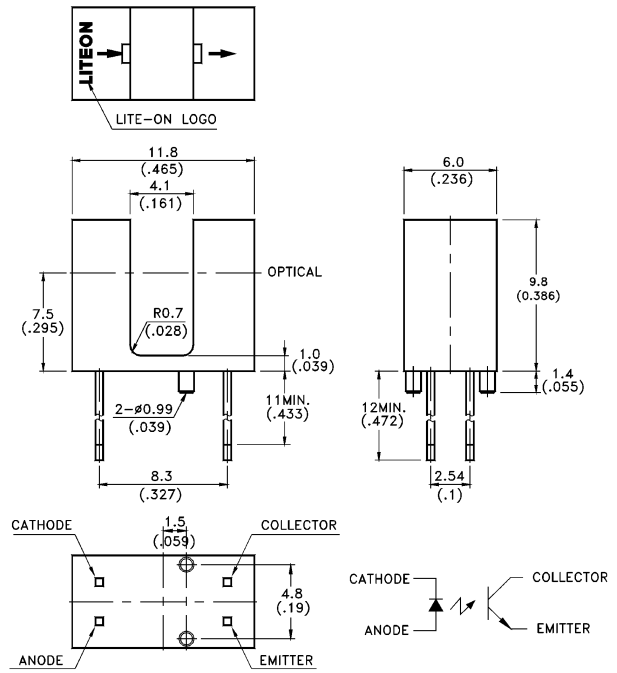
Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is ± 0.25 mm (.010").
3. Lead spacing is measured where the leads emerge from the package.
4. Specifications are subject to change without notice.

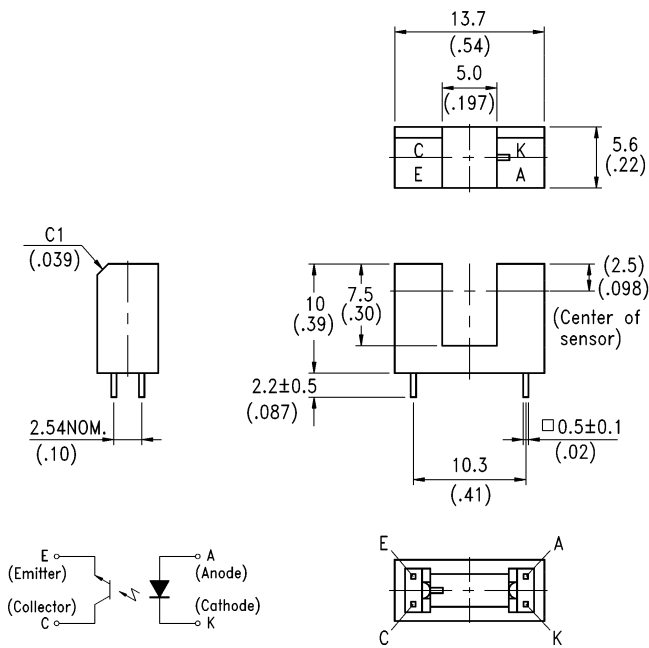
LTH-301-07



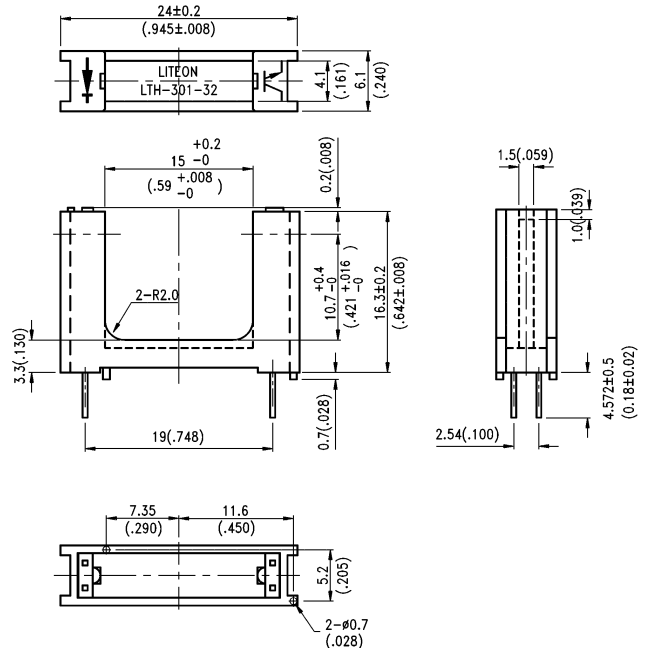
LTH-301-19



LTH-301-23

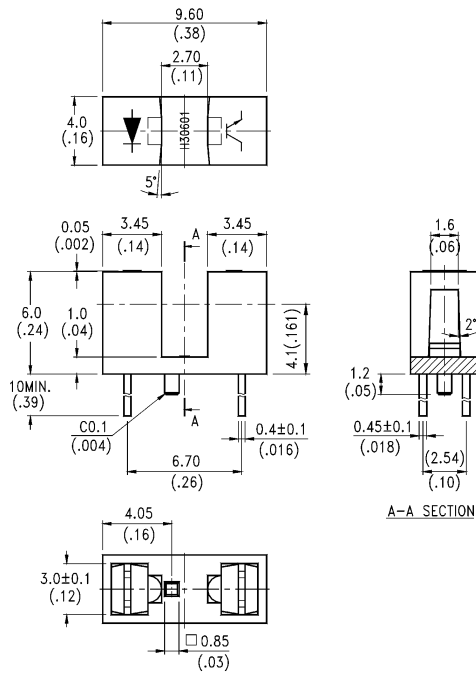


LTH-301-32

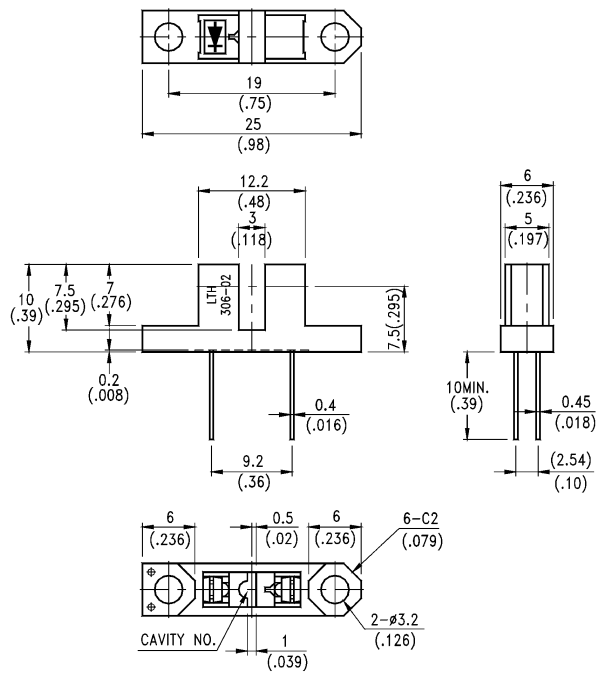


PHOTOINTERRUPTERS

LTH-306-01



LTH-306-02



Absolute Maximum Ratings at Ta=25 °C

Parameter		Symbol	Maximum Rating	Unit
Input LED	Continuous Forward Current	IF	60	mA
	Reverse Voltage	VR	5	V
	Peak Forward Current (Pulse Wide=10 μ S,300PPS)	ICP	1	A
	Power Dissipation	PD	75	mW
Output Phototransistor	Collector Current	IC	20	mA
	Power Dissipation	PC	100	mW
	Collector-emitter Voltage	VCEO	30	V
	Emitter-collector Voltage	VECO	5	V
Operating Temperature Range		Topr	-25 °C to 85 °C	
Storage Temperature Range		Tstg	-40 °C to 100 °C	
Lead Soldering Temperature [1.6mm(.063 in.) from body]		TS	260 °C for 5 seconds	

Electrical Optical Characteristics at Ta=25 °C

Parameter	Symbol	Part No.	Min.	Typ.	Max.	Unit	Test Condition
Input LED							
Forward Voltage	V _F			1.2	1.6	V	I _F =20mA
Reverse Current	I _R				100	μ A	V _R =5V
Output Phototransistor							
Collector-emitter Breakdown Voltage	BV _{CEO}		30			V	I _C =1mA
Emitter-collector Breakdown Voltage	BV _{ECO}		5			V	I _E =0.1mA
Collector Dark Current	I _{CEO}				100	nA	V _{CE} =10V
Coupler							
Collector-emitter Saturation Voltage	V _{CE(sat)}	LTH-301A			0.4	V	I _C =0.5mA, I _F =20mA
		LTH-301-05			0.4		I _C =0.5mA, I _F =20mA
		LTH-301-07			0.4		I _C =0.5mA, I _F =20mA
		LTH-301-19			0.4		I _C =1.5mA, I _F =20mA
		LTH-301-23			0.4		I _C =0.4mA, I _F =20mA
		LTH-301-32			0.4		I _C =0.4mA, I _F =20mA
		LTH-306-01			0.4		I _C =5.0mA, I _F =20mA
		LTH-306-02			0.4		I _C =0.5mA, I _F =20mA
On State Collector Current	I _{C(ON)}	LTH-301A	0.5			mA	V _{CE} =5V, I _F =20mA
		LTH-301-05	0.5				
		LTH-301-07	0.4				
		LTH-301-19	1.5				
		LTH-301-23	0.4				
		LTH-301-32	0.4				
		LTH-306-01	5.0				
		LTH-306-02	0.5				
Response Time	Rise Time	t _r			3	15	μ S
	Fall Time	t _f			4	20	

Typical Electrical/Optical Characteristic Curves (25 °C Ambient Temperature Unless Otherwise Noted)

Fig.1 Power Dissipation vs. Ambient Temperature

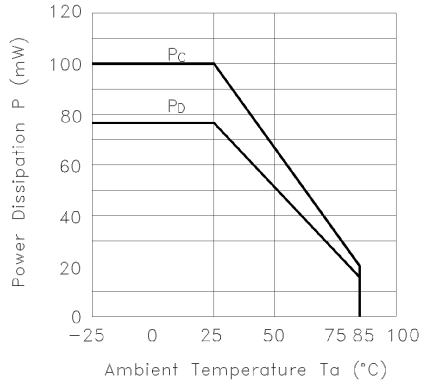


Fig.2 Forward Current I_F vs. Forward Voltage V_F

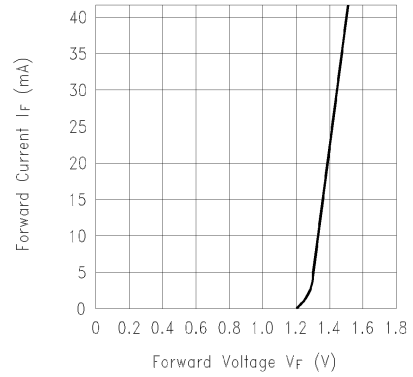


Fig.3 Collector Current vs. Collector-emitter Voltage

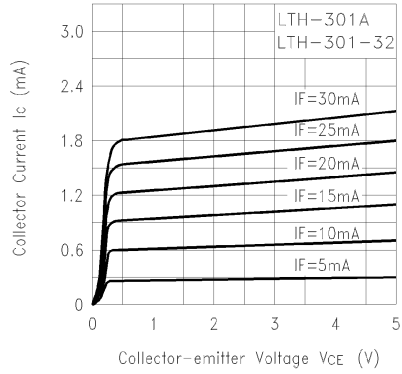


Fig.4 Collector Current vs. Collector-emitter Voltage

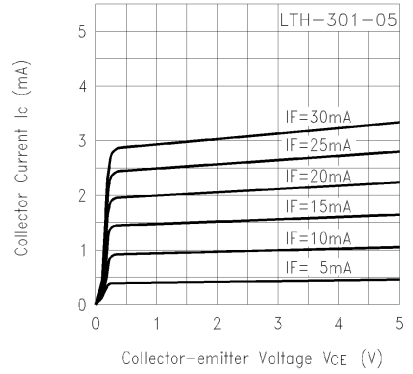


Fig.5 Collector Current vs. Collector-emitter Voltage

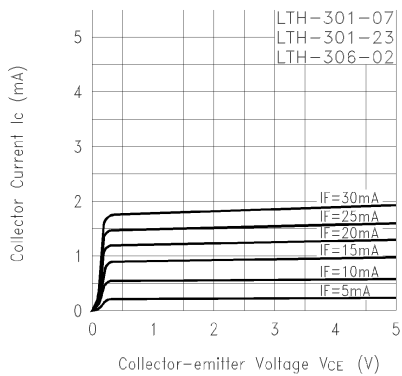
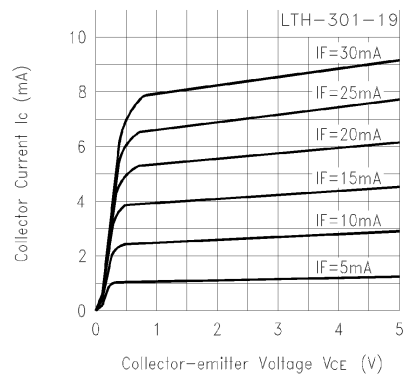


Fig.6 Collector Current vs. Collector-emitter Voltage



Typical Electrical/Optical Characteristic Curves (25 °C Ambient Temperature Unless Otherwise Noted)

Fig.7 Collector Current vs. Collector-emitter Voltage

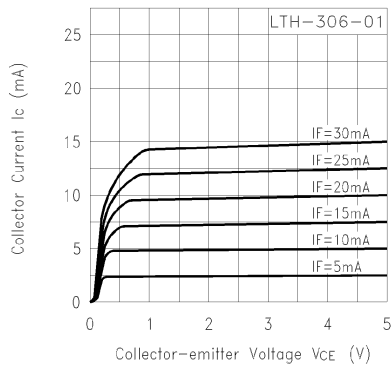


Fig.8 Collector Current vs. Ambient Temperature

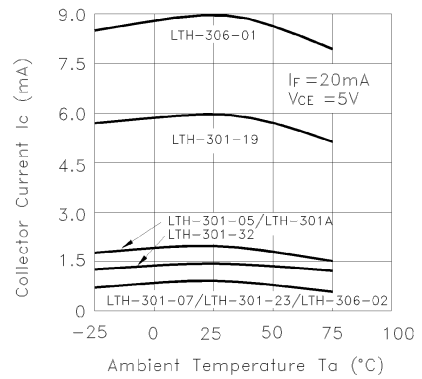


Fig.9 Collector-emitter Saturation Voltage vs. Ambient Temperature

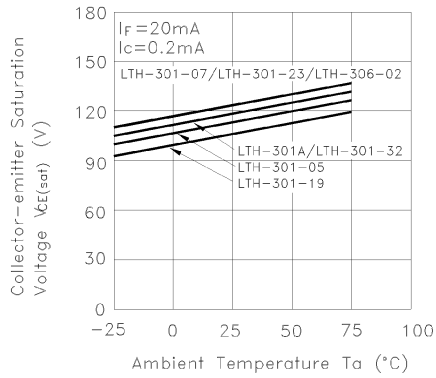
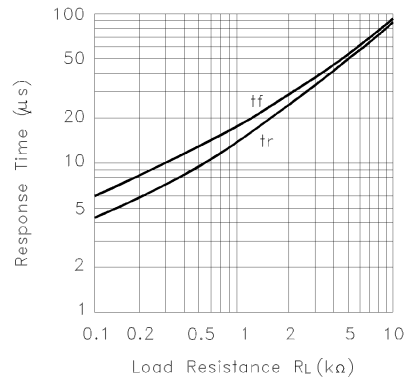


Fig.10 Response Time vs. Load Resistance



Test Circuit for Response Time

